UNISONIC TECHNOLOGIES CO., LTD

UTG10N120LLS1

Preliminary

Insulated Gate Bipolar Transistor

1200V, SMPS N-CHANNEL IGBT

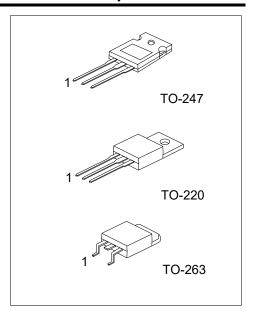
■ DESCRIPTION

The UTC **UTG10N120LLS1** is a N-channel IGBT. it uses UTC's advanced technology to provide customers with high input impedance, high switching speed and low conduction loss, etc.

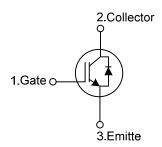
The UTC **UTG10N120LLS1** is suitable for high voltage switching, high frequency switch mode power supplies.

■ FEATURES

- * High switching speed
- * High avalanche ruggedness
- * Low saturation voltage: $V_{CE(SAT).Typ.}$ = 1.45V @ Ic=10A, V_{GE} =15V (T_C =25°C)



■ SYMBOL



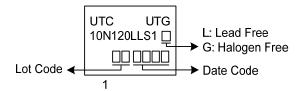
■ ORDERING INFORMATION

Ordering Number		Deelsere	Pin Assignment			Daakina	
Lead Free	Halogen Free	Package	1	2	3	Packing	
UTG10N120LLS1L-TA3-T	UTG10N120LLS1G-TA3-T	TO-220	G	С	Е	Tube	
UTG10N120LLS1L-TQ2-T	UTG10N120LLS1G-TQ2-T	TO-263	G	С	Е	Tube	
UTG10N120LLS1L-TQ2-R	UTG10N120LLS1G-TQ2-R	TO-263	G	С	Е	Tape Reel	
UTG10N120LLS1L-T47-T	UTG10N120LLS1G-T47-T	TO-247	G	С	Е	Tube	

Note: Pin Assignment: G: Gate C: Collector E: Emitter

UTG10N120LLS1G-TA3-T (1)Packing Type (1) T: Tube, R: Tape Reel (2) TA3: TO-220, TQ2: TO-263, T47: TO-247 (3)Green Package (3) G: Halogen Free and Lead Free, L: Lead Free

■ MARKING



■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise noted)

PARAMETER		SYMBOL	RATINGS	UNIT	
Collector-Emitter Voltage		V _{CES}	1200	V	
Gate-Emitter Voltage		.,	±20	V	
Transient Gate-emitter voltage (tp < 5 ms)		V_{GES}	±25	V	
Continuous Collector Current	T _C =25°C	- Ic	20	Α	
	T _C =100°C		10	Α	
Collector Current Pulsed (Note 1)		I _{CM}	40	Α	
Diode Forward Current	T _C =25°C	- I _F	20	Α	
	T _C =100°C		10	Α	
Short Circuit Withstand Time $V_{GE} = 15V, V_{CC} \le 200V$		t _{SC}			
				μs	
Allowed number of short circuits < 1000			8		
Time between short circuits: ≥ 1.0s T _{VJ} = 25°C					
Power Dissipation (Tc=25°C)	TO-220	P _D	96	W	
	TO-263		30	V V	
	TO-247		245	W	
Operating Junction Temperature		TJ	-40 ~ +150	°C	
Storage Temperature Range		T _{STG}	-55 ~ + 150	°C	

Notes: 1. Absolute maximum ratings are stress ratings only and functional device operation is not implied. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

■ THERMAL DATA

PARAMETER		SYMBOL	RATING	UNIT	
Junction to Case	TO-220 TO-263	θις	1.3	°C/W	
	TO-247		0.51	°C/W	

^{2.} Pulse width limited by maximum junction temperature.

■ **ELECTRICAL CHARACTERISTICS** (T_C=25°C, unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS							
Collector-Emitter Breakdown Voltage	BV _{CES}			1200			V
Collector Cut-Off Current	I _{CES}	V _{CE} =1200V, V _{GE} =0V				5	μA
G-E Leakage Current	I _{GES}	V _{CE} =0V, V _{GE} =±20V				±250	nA
ON CHARACTERISTICS							
Gate to Emitter Threshold Voltage	$V_{\text{GE(TH)}}$	I _C =250μA, V _{CE} =V _{GE}		4.5		7.6	V
Collector to Emitter Saturation Voltage	V _{CE(SAT)}	I _C =10A, V _{GE} =15V	T _C =25°C		1.45	2.1	V
			T _C =125°C		2.2		V
DYNAMIC CHARACTERISTICS							
Input Capacitance	CIES	V _{CE} =25V, V _{GE} =0V, f=1MHz			1000		рF
Output Capacitance	C _{OES}				58.7		pF
Reverse Transfer Capacitance	C _{RES}				30.7		рF
SWITCHING CHARACTERISTICS							
Total Gate Charge	Q_{G}	V _{CE} =600V, I _C =10A, V _{GE} =15V			83.6		nC
Gate-Emitter Charge	Q_GE				13.7		nC
Gate-Collector Charge	Q_GC				49.7		nC
Turn-On Delay Time	t _{DON)}	V _{CC} =600V, I _C =10A, R _G =5Ω, V _{GE} =0~15V, L=500μH			7.6		ns
Rise Time	t_R				13.5		ns
Turn-Off Delay Time	t _{DOFF)}				100.6		ns
Fall Time	t_{F}				307.9		ns
Turn-On Switching Loss	Eon				0.62		mJ
Turn-Off Switching Loss	E _{OFF}			1.1		mJ	
SOURCE- DRAIN DIODE RATINGS A	ND CHARAC	TERISTICS					
Forward Voltage Drop	VF	I _F =10A				2.5	V
Reverse Recovery Time	t _{rr}	I _F =10A, dI/dt=100A/µS, V _{CC} =400V			51		ns
Reverse Recovery Charge	Q_{rr}				0.65		μC

■ TEST CIRCUIT AND WAVEFORMS

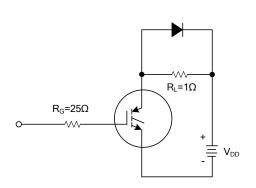


Fig 1. INDUCTIVE SWITCHING TEST CIRCUIT

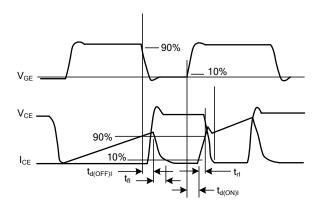


Fig 2. SWITCHING TEST WAVEFORMS

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